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RFMD
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SGA-1163(Z)

DC to 6000MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

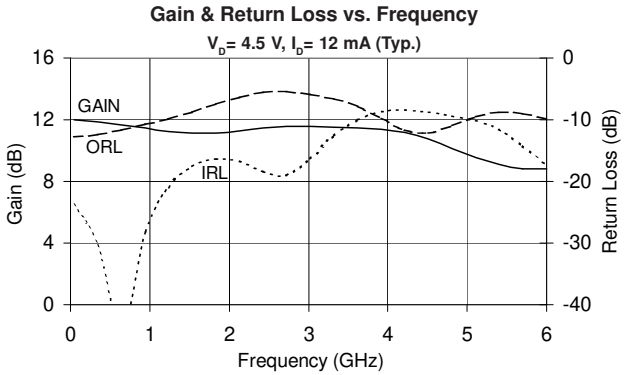
Package: SOT-363

Product Description

RFMD's SGA-1163(Z) is a SiGe HBT MMIC amplifier that offers excellent isolation and flat gain response for applications to 6GHz. A 2-stage design provides high isolation up to 40dB at 2GHz and is fabricated using the latest SiGe HBT 50GHz FT process, featuring one-micron emitters with VCEO>7V. This unconditionally stable amplifier has less than 1dB gain drift over 125°C operating range (-40°C to +85°C) and is ideal for use as a buffer amplifier in oscillator applications covering cellular, ISM, and narrowband PCS bands.

Optimum Technology Matching® Applied

- ☐ GaAs HBT
- ☐ GaAs MESFET
- ☐ InGaP HBT
- ☐ SiGe BiCMOS
- ☐ Si BiCMOS
- ☑ SiGe HBT
- ☐ GaAs pHEMT
- ☐ Si CMOS
- ☐ Si BJT
- ☐ GaN HEMT
- ☐ RF MEMS



Features

- DC to 6000MHz Operation
- Excellent Isolation, >50dB at 900MHz
- Single Supply Voltage
- Unconditionally Stable
- Cascadable 50Ω

Applications

- Buffer Amplifier for Oscillator Applications
- Cellular, PCS, GSM, UMTS
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Small Signal Gain	11.0	12.5	14.0	dB	850MHz
	10.0	11.5	13.0	dB	1950MHz
		11.4		dB	2400MHz
Output Power at 1dB Compression		-3.3		dBm	850MHz
	-4.0	-2.5		dBm	1950MHz
Output Third Order Intercept Point		7.9		dBm	850MHz
	4.3	6.3		dBm	1950MHz
Bandwidth		6000		MHz	
Input Return Loss		16.4		dB	1950MHz
Output Return Loss		7.0		dB	1950MHz
Noise Figure		3.4		dB	1950MHz
Device Operating Voltage	4.2	4.5	4.8	V	
Device Operating Current	10	12	14	mA	
Thermal Resistance		255		°C/W	junction - lead

Test Conditions: V_S=8V, I_D=12mA Typ., T_L=25°C. OIP_3 Tone Spacing=1MHz, P_{OUT} per tone=-20dBm, R_{BIAS}=300Ω, Z_S=Z_L=50Ω

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Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current (I_D)	24	mA
Device Voltage (V_D)	6	V
RF Input Power	+12	dBm
Junction Temp (T_J)	+150	°C
Operating Temp Range (T_L)	-40 to +85	°C
Storage Temp	+150	°C
ESD Rating - Human Body Model (HBM)	Class 0	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.
Bias Conditions should also satisfy the following expression:
$I_D V_D < (T_J - T_L) / R_{TH, j-l}$

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

Typical Performance at Key Operating Frequencies

Parameter	Unit	100 MHz	500 MHz	850 MHz	1950 MHz	2400 MHz	3500 MHz
Small Signal Gain, G	dB	12.0	11.8	12.5	11.5	11.4	11.5
Output Third Order Intercept Point, OIP_3	dBm		8.7	7.9	6.3	5.7	
Output Power at 1dB Compression, P_{1dB}	dBm		-3.8	-3.3	-4.6	-4.4	
Input Return Loss, IRL	dB	25.2	33.9	32.6	16.4	18.3	10.9
Output Return Loss, ORL	dB	12.7	12.0	11.0	7.0	5.6	7.3
Reverse Isolation, S_{12}	dB	47.8	57.0	50.4	33.5	30.8	28.3
Noise Figure, NF	dB		3.1	3.1	3.4	3.4	

Test Conditions: V_S=8V I_D=12mA Typ. OIP_3 Tone Spacing=1MHz, P_{OUT} per tone=-20dBm R_{BIAS}=300Ω
T_L=25°C Z_S=Z_L=50Ω

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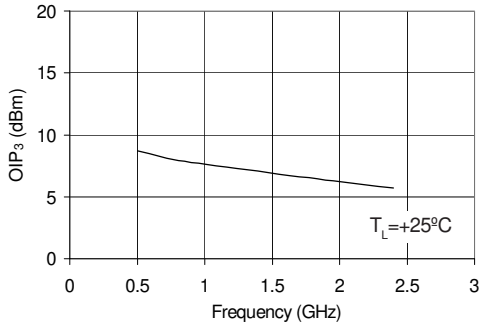
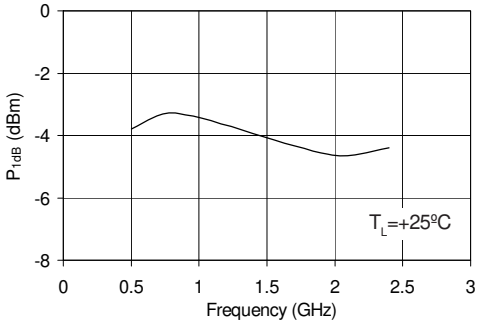
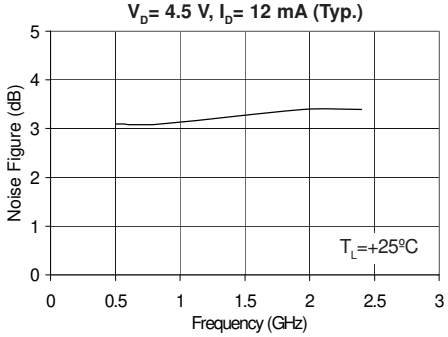
OIP_3 vs. Frequency
V_D= 4.5 V, I_D= 12 mA (Typ.)



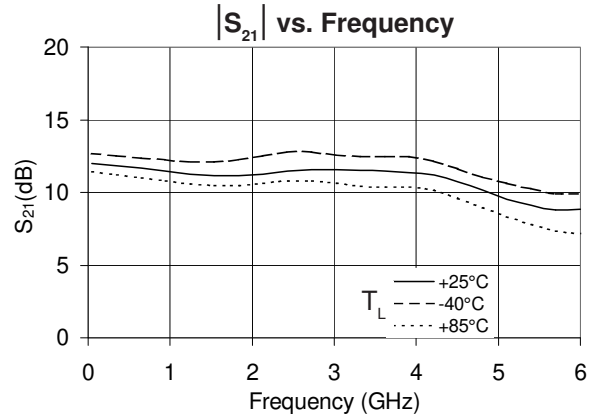
P_{1dB} vs. Frequency
V_D= 4.5 V, I_D= 12 mA (Typ.)

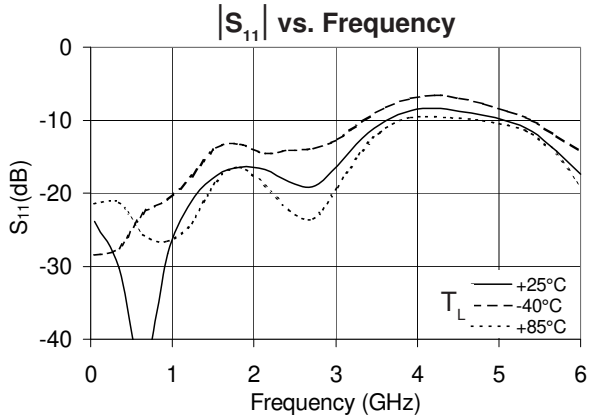


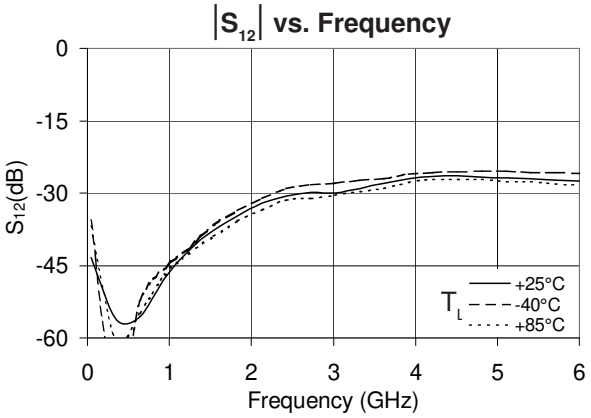
Noise Figure vs. Frequency
V_D= 4.5 V, I_D= 12 mA (Typ.)

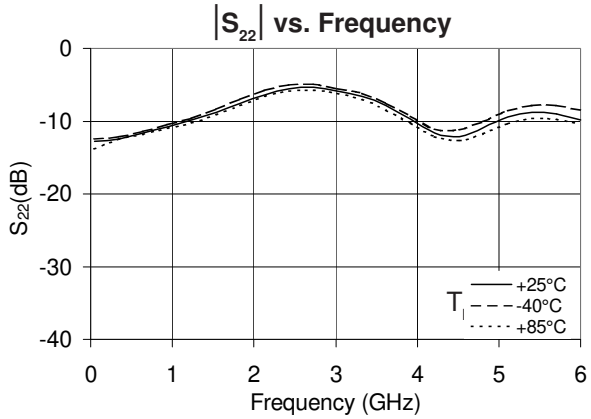


Typical RF Performance Over Temperature (Bias: V_D= 4.5 V, I_D= 12 mA (Typ.))









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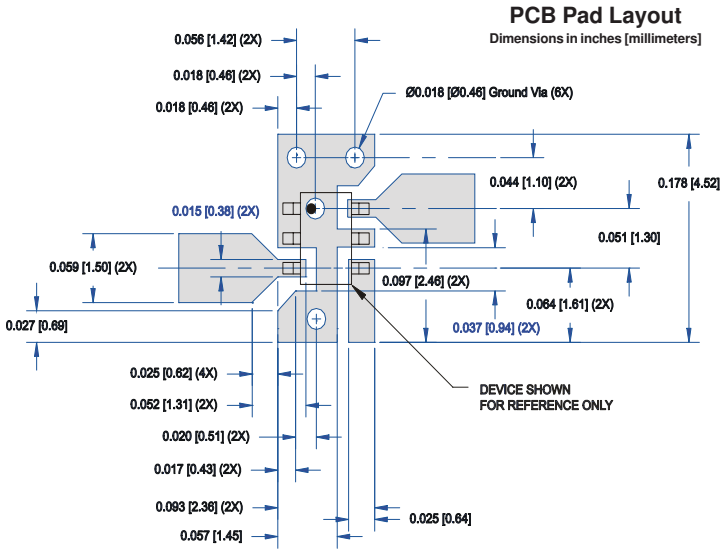
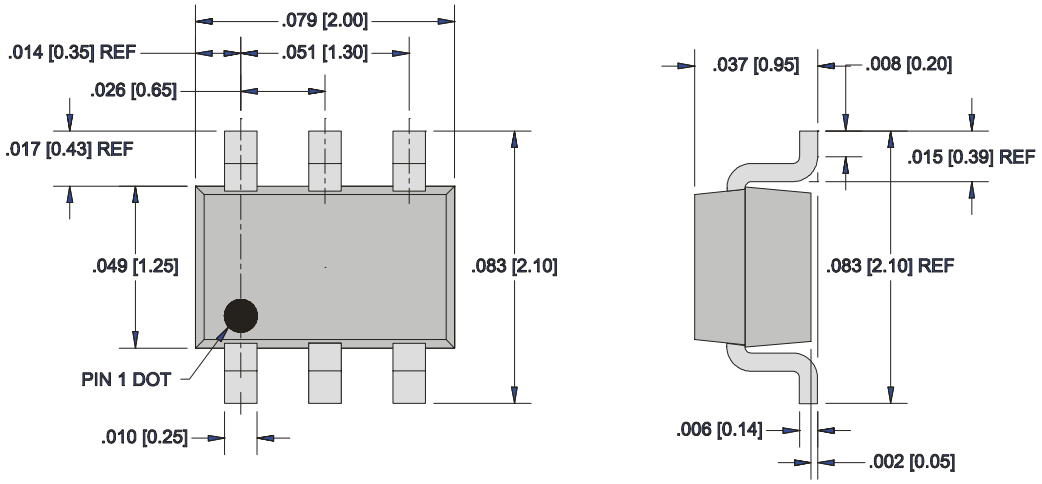
Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
4	VCC	Voltage supply connection. Use bypass capacitors as indicated by the basic application circuit.
1, 2, 5	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
6	RF OUT	RF output pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper operation.

Suggested Pad Layout



Package Drawing

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.



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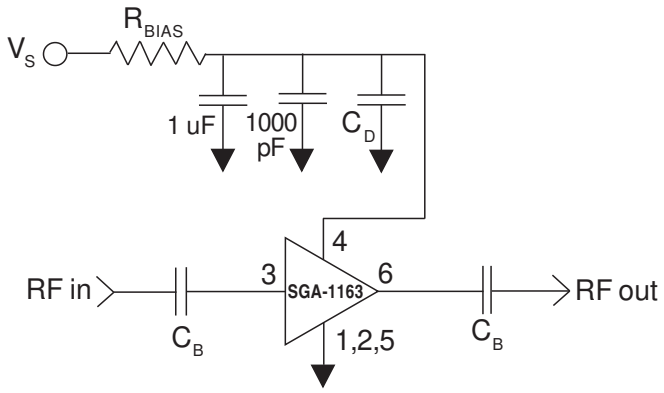
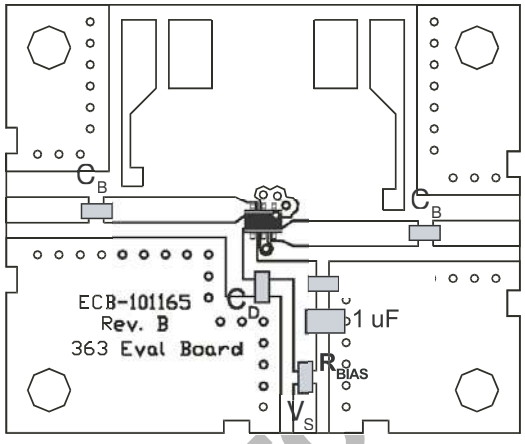
Application Schematic



Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C_B	220 pF	100 pF	68 pF	56 pF	39 pF
C_D	100 pF	68 pF	22 pF	22 pF	15 pF

Recommended Bias Resistor Values for I_D=12mA $R_{BIAS}=(V_S-V_D) / I_D$				
Supply Voltage(V_S)	6 V	8 V	9 V	12 V
R_{BIAS}	130 Ω	300 Ω	390 Ω	620 Ω
Note: R_{BIAS} provides DC bias stability over temperature.				

Evaluation Board Layout



1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes as shown.

3. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

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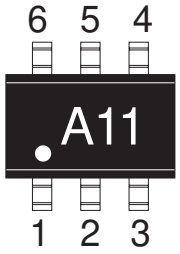
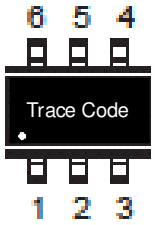
Part Identification Marking



RoHS Compliant part indicated with a “A11Z” on part marking.

Alternate Marking with Trace Code Only



Ordering Information

Part Number	Reel Size	Devices/Reel
SGA-1163	7”	3000
SGA-1163Z	7”	3000

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